RELIABILITY REPORT

FOR

MAX4599ExT

PLASTIC ENCAPSULATED DEVICES

July 10, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

Jim Pedicord Quality Assurance Reliability Lab Manager Reviewed by

Bryan J. Preeshl Quality Assurance Executive Director

Conclusion

The MAX4599 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

IDevice Description	VQuality Assurance Information
IIManufacturing Information	VIReliability Evaluation
IIIPackaging Information	IVDie Information
	Attachments

I. Device Description

A. General

The MAX4599 single-pole/double-throw (SPDT) switch operates from a +2.0V to +5.5V single supply. It offers 60-ohms max on-resistance (R_{ON}) at +5V and fast switching times (t_{ON} = 30ns max, t_{OFF} = 25ns max).

The MAX4599 features excellent R_{ON} flatness (4 ohms max) and matching (1-ohm max) between channels. This device also offers 5pC max charge injection.

The MAX4599 is available in tiny 6-pin SC70 and SOT23 packages.

B. Absolute Maximum Ratings

<u>ltem</u>	Rating
Voltage Referenced to GND	
V+	-0.3V to +6V
IN, COM, NO, NC (Note 1)	-0.3V to $(V++0.3V)$
Continuous Current (any terminal)	±20mA
Peak Current, COM, NO, NC (pulsed at 1ms, 10% duty cycle) ±40mA
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Continuous Power Dissipation (TA = +70°C)	
6-Pin SC70	245mW
6-Pin SOT23	571mW
Derates above +70°C	
6-Pin SC70	3.1mW/°C
6-Pin SOT23	7.1mW/°C

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

II. Manufacturing Information

A. Description/Function: Low-Voltage, Single-Supply, SPDT Analog Switch in SC70

B. Process: S12 (Standard 1.2 micron silicon gate CMOS)

C. Number of Device Transistors: 89

D. Fabrication Location: California or Oregon, USA

E. Assembly Location: Philippines, Thailand or Malaysia

F. Date of Initial Production: October, 1997

III. Packaging Information

A. Package Type: 6-Pin SC70 6-Pin SOT23

B. Lead Frame: Copper Copper

C. Lead Finish: Solder Plate Solder Plate

D. Die Attach: Non-Conductive Epoxy Non-Conductive Epoxy

E. Bondwire: Gold (1 mil dia.) Gold (1 mil dia.)

F. Mold Material: Epoxy with silica filler Epoxy with silica filler

G. Assembly Diagram: # 05-1201-0150 #05-1201-0149

H. Flammability Rating: Class UL94-V0 Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-112: Level 1 Level 1

IV. Die Information

A. Dimensions: 32 x 30 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn)

F. Minimum Metal Spacing: 1.2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Reliability Lab Manager)

Bryan Preeshl (Executive Director) Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \underbrace{\frac{1}{\text{MTTF}}}_{} = \underbrace{\frac{1.83}{192 \text{ x } 4389 \text{ x } 80 \text{ x } 2}}_{} \text{(Chi square value for MTTF upper limit)}$$

$$\underbrace{}_{} \text{Temperature Acceleration factor assuming an activation energy of } 0.8eV$$

$$\lambda = 13.57 \times 10^{-9}$$

 λ = 13.57 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Attached Burn-In Schematic (Spec. # 06-5514) shows the static Burn-In circuit. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (RR-1M).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The AH67 die type has been found to have all pins able to withstand a transient pulse of ± 1500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 50 mA.

Table 1 Reliability Evaluation Test Results

MAX4599ExT

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	(Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		80	0
Moisture Testin	g (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SC70 SOT23	77 77	0 0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Stre	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

TABLE II. Pin combination to be tested. 1/2/

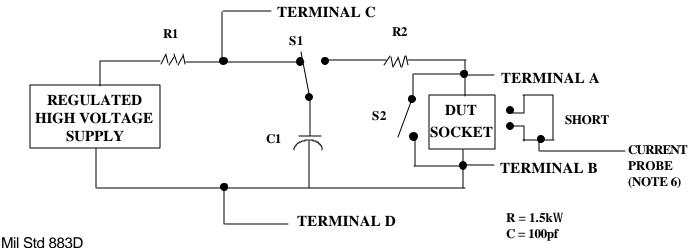
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)		
1.	All pins except V _{PS1} 3/	All V _{PS1} pins		
2.	All input and output pins	All other input-output pins		

- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

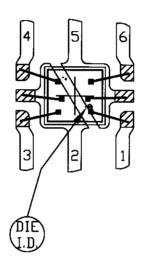
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Method 3015.7 Notice 8

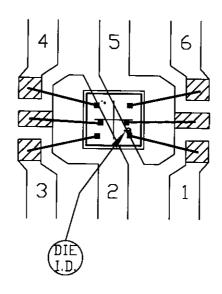


NOTE: CAVITY DOWN

PKG.CODE:	X6S-1	
CAV./PAD	SIZE:	 PKG.
	<u>36×34</u>	DESIGN

APPROVALS DATE

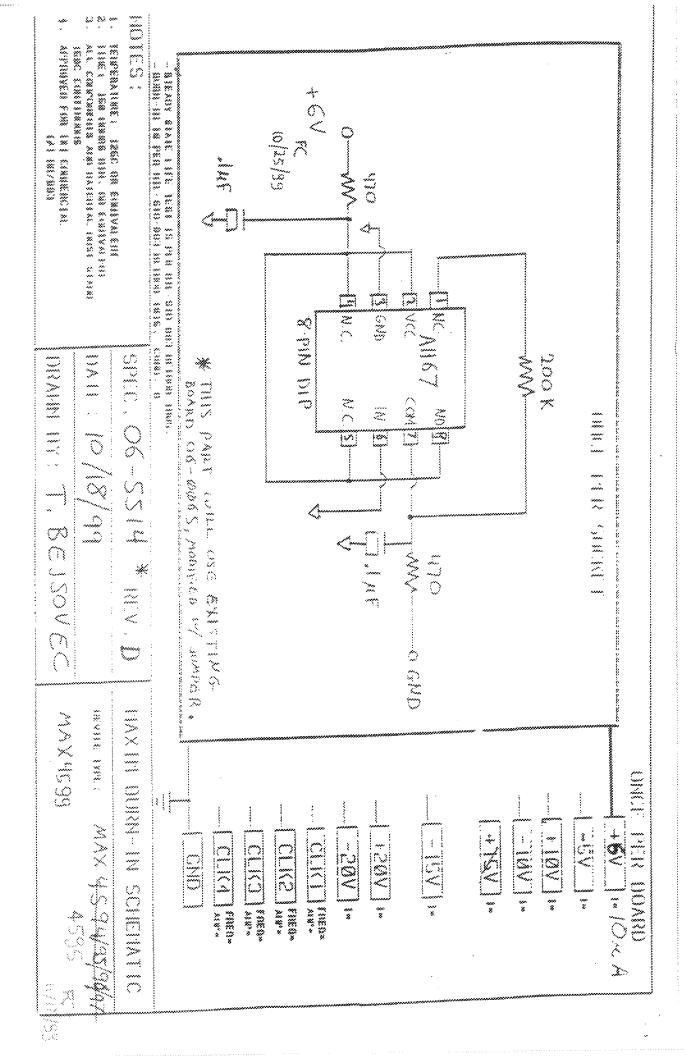




NOTE: USE NON-CONDUCTIVE EPOXY ONLY

BONDABLE AREA

PKG.CODE: U6S-3		APPROVALS	DATE	/VI/IXI	///
CAV./PAD SIZE:	PKG.			<u>† </u>	REV.:
64×46	DESIGN			05-1201-0149	A



PROCESS - SINCIPX